AMT1707A 1 - 20GHz SPST Switch Chip



Key Features :

- Frequency range : 1 20GHz
- Insertion loss : 1.3dB
- Isolation : 50dB
- Input standing wave : 1.2
- Switch ON input/output standing wave : 1.2
- Switch OFF output standing wave : 1.3
- Control method : TTL
- Supply : +5V/1mA
- Chip dimensions : 1.5mm x 0.8mm x 0.1mm
- Applications : wireless communication, transceiver module, radio telecommunication etc.

Description :

AMT1707A is a high performance FET SPST switch chip, it is designed by Gallium Arsenide (GaAs) pHEMT process. This chip is designed with ground through metal vias on the back technology. All chip products p are 100% RF tested. The chip uses +5V supply, TTL level control, typical insertion loss is 1.3dB, isolation is 50dB, input/output standing wave is 1.2.

Absolute Maximum Ratings (Ta = 25°C)

Symbol	Parameter	Value	Remark		
V1/V2	Control voltage	0.5V/5.5V			
Pin	Input Power	25dBm			
Tm	Sintering Temperature	310°C	30s, N ₂ protection		
Tstg	Storage Temperature	-65 ~ +150°C			

[1] Operation outside any of the Absolute Maximum Ratings may cause permanent device damage.

Electrical Characteristics (Ta = 25°C)

Symbol	Parameter	Test Conditions	Value		Unit	
			Min	Typical	Max	
VSWRin	Input standing wave		-	1.2	-	-
VSWRout(On)	ON state output standing wave		-	1.2	-	-
VSWRout(Off)	OFF state output standing wave	F : 2 ~ 20GHz	-	1.3	-	-
IL	Insertion Loss		-	1.3	1.8	dB
ISO	Isolation		46	50	-	dB

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Typical Performance



Switch ON State Input Standing Wave Curve



Switch OFF State Output Standing Wave Curve





Switch ON State Output Standing Wave Curve



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Chip Dimensions (Unit : µm)



Chip Layout Diagram



Pad Definition

No.	Symbo	Function Description	Dimension
1	RF1	RF signal input port, external connect to 50 Ω system, internal built in DC blocking	100µm*100µm
		capacitor	
2	RF2	RF signal output port, external connect to 50 Ω system, internal built in DC	100µm*100µm
		blocking capacitor	
3	CTRL	Supply voltage control port, see Truth Table for control logic	100µm*100µm
4	VDD	+5V supply	100µm [*] 100µm

Truth Table

	CTRL	VDD
ON	0V	5V
OFF	5V	5V

Please see Appendix A for details.

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